











MC33063A-Q1

SLLS654C -APRIL 2005-REVISED DECEMBER 2014

MC33063A-Q1 1.5-A Peak Boost, Buck, Inverting Switching Regulator

Features

- AEC-Q100 Qualified With the Following Results:
 - Device HBM ESD Classification Level 2
 - Device CDM ESD Classification Level C4B
- Wide Input Voltage Range: 3 V to 40 V
- High Output Switch Current: Up to 1.5 A
- Adjustable Output Voltage
- Oscillator Frequency: Up to 100 kHz
- Precision Internal Reference: 2%
- **Short-Circuit Current Limiting**
- Low Standby Current

2 Applications

Automotive: Buck. Boost. and Inverting **Topologies**

3 Description

The MC33063A-Q1 device is an easy-to-use IC containing all the primary circuitry needed for building simple DC-DC converters. The device primarily consists of an internal temperature-compensated reference, a comparator, an oscillator, a PWM controller with active current limiting, a driver, and a high-current output switch. Thus, the device requires minimal external components to build converters in the boost, buck, and inverting topologies.

The MC33063A-Q1 device is characterized for operation from -40°C to 125°C.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
MC33063A-Q1	SOIC (8)	4.90 mm × 3.91 mm

(1) For all available packages, see the orderable addendum at the end of the datasheet.

Simplified Schematic

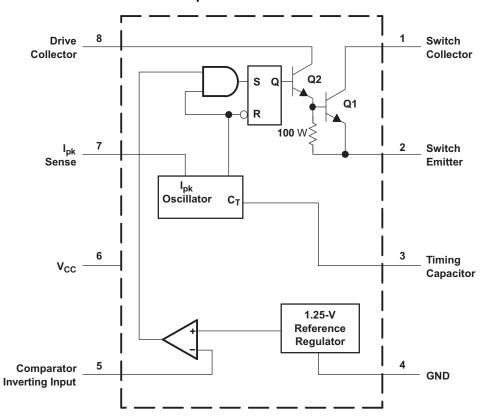




Table of Contents

7.1 Overview	1 7.1 Overview	Conturas	4
		Features	1
9		Applications	2
7.3 Feature Description	7.3 Feature Description	Description	3
7.4 Device Functional Modes	7.4 Davidas Everstianal Madas	Revision History	4
Application and Implementation	9 Application and Implementation	Pin Configuration and Functions	5
8.1 Application Information	8.1 Application Information	Specifications	6
8.2 Typical Applications	8.2 Typical Applications	-	U
Power Supply Recommendations	9 Power Supply Pecommendations	6.1 Absolute Maximum Ratings	
Layout	40 Lavaut	6.3 Recommended Operating Conditions	
10.1 Layout Guidelines	40.4	6.4 Thermal Information	
10.2 Layout Example	40.0 Leavest Francis	6.5 Oscillator Characteristics	
Device and Documentation Support	44 Davies and Desumentation Compant	6.6 Output Switch Characteristics	
11.1 Trademarks	44.4 = 1 1	6.7 Comparator Characteristics	
11.2 Electrostatic Discharge Caution	44.0 El 1 1 1 B 1 1 0 1	6.8 Total Device Characteristics	
11.3 Glossary	44.0 01	6.9 Typical Characteristics	
		Detailed Description	7
		Detailed Description	•

4 Revision History

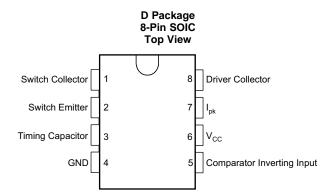
Changes from Revision B (September 2008) to Revision C

Page

Added the ESD Ratings table, Feature Description section, Device Functional Modes section, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation



5 Pin Configuration and Functions



Pin Functions

	PIN	I/O	DESCRIPTION
NO.	NAME	1/0	DESCRIPTION
1	Switch Collector	_	Switch Collector
2	Switch Emitter	_	Switch Emitter
3	Timing Capacitor	_	Timing Capacitor
4	GND	_	Ground
5	Comparator Inverting Input	I	Comparator Inverting Input
6	V _{CC}	1	Supply
7	I _{PK}	I	Peak Current
8	Driver Collector	_	Driver Collector

Copyright © 2005–2014, Texas Instruments Incorporated



6 Specifications

6.1 Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

	MIN	MAX	UNIT
Supply voltage, V _{CC}		40	V
Comparator Inverting Input voltage range, V _{IR}	-0.3	40	V
Switch Collector voltage, V _{C(switch)}		40	V
Switch Emitter voltage, V _{E(switch)} V _{PIN1} = 40 V		40	V
Switch Collector to Switch Emitter voltage, V _{CE(switch)}		40	V
Driver Collector voltage, V _{C(driver)}		40	V
Driver Collector current, I _{C(driver)}		100	mA
Switch current, I _{SW}		1.5	Α
Operating virtual junction temperature, T _J		150	°C
Storage temperature, T _{stg}	-65	150	°C

⁽¹⁾ Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

				VALUE	UNIT
		Human body model (HBM), per AEC Q100-002 ⁽¹⁾		±2000	
V _(ESD)	Electrostatic discharge	Charged device model (CDM), per AEC Q100-011	Corner pins (1, 4, 5, and 8)	±750	V
			Other pins	±500	

⁽¹⁾ AEC Q100-002 indicates HBM stressing is done in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

6.3 Recommended Operating Conditions

		MIN	NOM MAX	UNIT
V_{CC}	Supply voltage	3	40	V
T_A	Operating free-air temperature	-40	125	°C

6.4 Thermal Information

		MC33063A-Q1	
	THERMAL METRIC ⁽¹⁾	D	UNIT
		8 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance (2)(3)	121.9	
R ₀ JC(top)	Junction-to-case (top) thermal resistance	68.1	
$R_{\theta JB}$	Junction-to-board thermal resistance	62.3	00/11/
Ψлт	Junction-to-top characterization parameter	19.9	°C/W
ΨЈВ	Junction-to-board characterization parameter	61.8	
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	N/A	

- (1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.
- (2) Maximum power dissipation is a function of $T_J(max)$, $R_{\theta JA}$, and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) T_A) / R_{\theta JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.

(3) The package thermal impedance is calculated in accordance with JESD 51-7.



6.5 Oscillator Characteristics

 $V_{CC} = 5 \text{ V}$, $T_A = \text{full operating range (unless otherwise noted)}$ (see block diagram)

	PARAMETER	TEST CONDITIONS	T _A	MIN	TYP	MAX	UNIT
f _{osc}	Oscillator frequency	$V_{PIN5} = 0 \text{ V, } C_T = 1 \text{ nF}$	25°C	24	33	42	kHz
I _{chg}	Charge current	V _{CC} = 5 V to 40 V	25°C	24	35	42	μΑ
I _{dischg}	Discharge current	V _{CC} = 5 V to 40 V	25°C	140	220	260	μΑ
I _{dischg} /I _{chg}	Discharge-to-charge current ratio	$V_{PIN7} = V_{CC}$	25°C	5.2	6.5	7.5	
V_{lpk}	Current-limit sense voltage	I _{dischg} = I _{chg}	25°C	250	300	350	mV

6.6 Output Switch Characteristics(1)

 $V_{CC} = 5 \text{ V}$, $T_A = \text{full operating range (unless otherwise noted)}$. See the *Functional Block Diagram*.

		*					
	PARAMETER	TEST CONDITIONS	T _A	MIN	TYP	MAX	UNIT
V _{CE(sat)}	Saturation voltage – Darlington connection	I _{SW} = 1 A, pins 1 and 8 connected	Full range		1	1.3	V
V _{CE(sat)}	Saturation voltage – non-Darlington connection (2)	I_{SW} = 1 A, R_{PIN8} = 82 Ω to V_{CC} , Forced β ~ 20	Full range		0.45	0.7	V
h _{FE}	DC current gain	I _{SW} = 1 A, V _{CE} = 5 V	25°C	50	75		
I _{C(off)}	Collector off-state current	V _{CE} = 40 V	Full range		0.01	100	μΑ

⁽¹⁾ Low duty-cycle pulse testing is used to maintain junction temperature as close to ambient temperature as possible.

Forced β of output switch = $I_{C,SW}$ / ($I_{C,driver}$ - 7 mA) \geq 10, where ~7 mA is required by the 100- Ω resistor in the emitter of the driver to forward bias the V_{be} of the switch.

6.7 Comparator Characteristics

 $V_{CC} = 5 \text{ V}$, $T_A = \text{full operating range (unless otherwise noted)}$. See the *Functional Block Diagram*.

		-					
	PARAMETER	TEST CONDITIONS	T _A	MIN	TYP	MAX	UNIT
V Threehold valte as			25°C	1.225	1.25	1.275	\/
V_{th}	Threshold voltage		Full range	1.21		1.29	V
ΔV_{th}	Threshold-voltage line regulation	V _{CC} = 5 V to 40 V	Full range		1.4	5	mV
I _{IB}	Input bias current	V _{IN} = 0 V	Full range		-20	-400	nA

6.8 Total Device Characteristics

V_{CC} = 5 V, T_A = full operating range (unless otherwise noted). See the *Functional Block Diagram*.

		<u> </u>	•			
	PARAMETER	TEST CONDITIONS	T _A	MIN	MAX	UNIT
I _{cc}	Supply current	V_{CC} = 5 V to 40 V, C_T = 1 nF, V_{PIN7} = V_{CC} , V_{PIN5} > V_{th} , V_{PIN2} = GND, All other pins open	Full range		4	mA

⁽²⁾ In the non-Darlington configuration, if the output switch is driven into hard saturation at low switch currents (≤300 mA) and high driver currents (≥30 mA), it may take up to 2 µs for the switch to come out of saturation. This condition effectively shortens the off time at frequencies ≥30 kHz, becoming magnified as temperature increases. The following output drive condition is recommended in the non-Darlington configuration:

6.9 Typical Characteristics

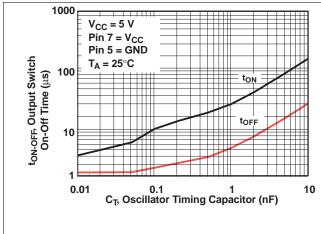


Figure 1. Output Switch On-Off Time vs Oscillator Timing Capacitor

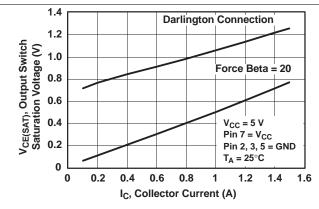


Figure 3. Output Switch Saturation Voltage vs Collector Current (Common-Emitter Configuration)

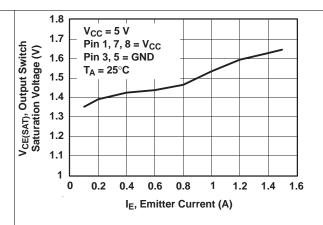


Figure 2. Output Switch Saturation Voltage vs Emitter Current (Emitter-Follower Configuration)

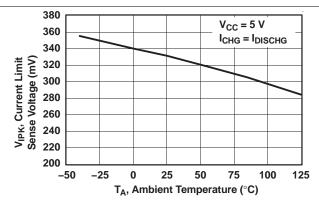


Figure 4. Current-Limit Sense Voltage vs Temperature

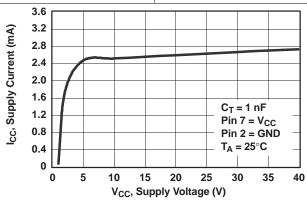


Figure 5. Standby Supply Current vs Supply Voltage

Submit Documentation Feedback

Copyright © 2005–2014, Texas Instruments Incorporated

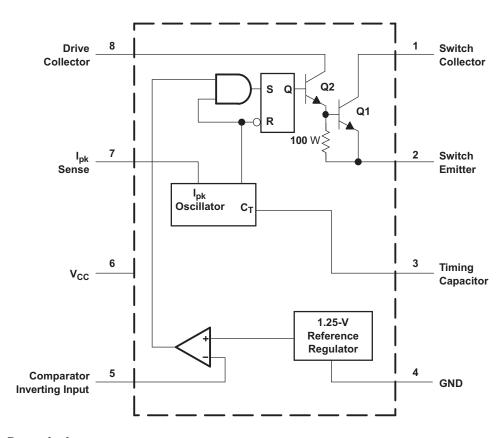


7 Detailed Description

7.1 Overview

The MC33063A-Q1 device primarily consists of an internal temperature-compensated reference, a comparator, an oscillator, a PWM controller with active current limiting, a driver, and a high-current output switch. The MC33063A-Q1 device requires minimal external components to build converters in the boost, buck, and inverting topologies.

7.2 Functional Block Diagram



7.3 Feature Description

The device includes the following components:

- Temperature-compensated reference voltage
- Oscillator
- Active peak-current limit
- Output switch
- Output voltage-sense comparator

7.3.1 Reference Voltage

The reference voltage is set at 1.25 V and is used to set the output voltage of the converter.

Copyright © 2005–2014, Texas Instruments Incorporated



Feature Description (continued)

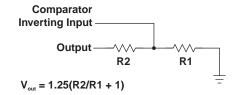


Figure 6. Reference Voltage Circuit

7.3.2 Current Limit

Current limit is accomplished by monitoring the voltage drop across an external sense resistor located in series with VCC and the output switch. The voltage drop developed across the sense resistor is monitored by the current-sense pin, lpk. When the voltage drop across the sense resistor becomes greater than the preset value of 330 mV, the current-limit circuitry provides an additional current path to charge the timing capacitor (CT) rapidly, to reach the upper oscillator threshold and, thus, limiting the amount of energy stored in the inductor. The minimum sense resistor is 0.2 W. Figure 7 shows the timing capacitor charge current versus current-limit sense voltage. To set the peak current, lpk = 330 mV/Rsense.

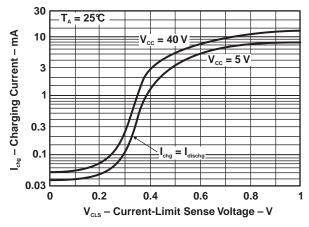


Figure 7. Timing Capacitor Charge Current vs Current-Limit Sense Voltage

7.3.3 Current Limit of Typical Operation Waveforms

The output switch is an NPN Darlington transistor. The collector of the output transistor is tied to pin 1, and the emitter is tied to pin 2. This allows the designer to use the MC33063 device in buck, boost, or inverter configurations. The maximum collector-emitter saturation voltage at 1.5 A (peak) is 1.3 V, and the maximum peak current of the output switch is 1.5 A. For higher peak output current, an external transistor can be used. Figure 8 shows the typical operation waveforms.



Feature Description (continued)

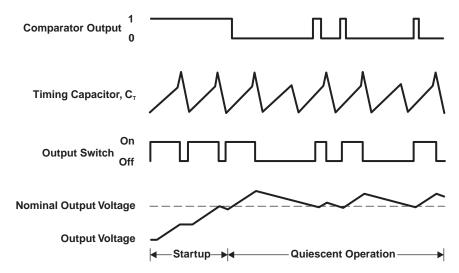


Figure 8. Typical Operation Waveforms

7.4 Device Functional Modes

The oscillator is composed of a current source and a current sink that charge and discharge the external timing capacitor (CT) between an upper and lower preset threshold. The typical charge current is 35 mA, and the typical discharge current is 200 mA, yielding approximately a 6:1 ratio. Thus, the ramp-up period is six times longer than that of the ramp-down period (see Figure 9). The upper threshold is 1.25 V, which is same as the internal reference voltage, and the lower threshold is 0.75 V. The oscillator runs constantly, at a pace controlled by the value of CT.

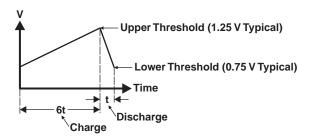


Figure 9. Oscillator Voltage Thresholds



8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The MC33063A-Q1 device requires minimal external components to build converters in the boost, buck, and inverting topologies.

8.2 Typical Applications

8.2.1 Step-Up Converter

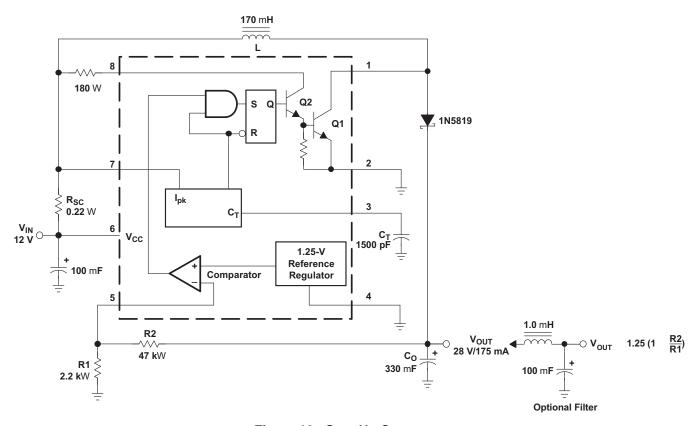


Figure 10. Step-Up Converter

Submit Documentation Feedback

Copyright © 2005–2014, Texas Instruments Incorporated



Typical Applications (continued)

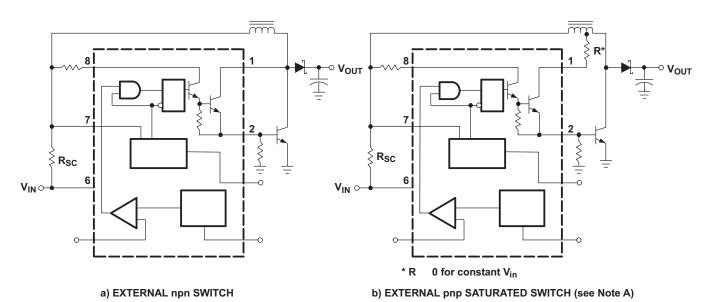


Figure 11. External Switches

8.2.1.1 Design Requirements

Table 1. Step-Up Converter

TEST	CONDITIONS	RESULTS
Line regulation	$V_{IN} = 8 \text{ V to } 16 \text{ V}, I_{O} = 175 \text{ mA}$	30 mV ± 0.05%
Load regulation	$V_{IN} = 12 \text{ V}, I_{O} = 75 \text{ mA to } 175 \text{ mA}$	10 mV ± 0.017%
Output ripple	$V_{IN} = 12 \text{ V}, I_{O} = 175 \text{ mA}$	400 mV _{PP}
Efficiency	$V_{IN} = 12 \text{ V}, I_{O} = 175 \text{ mA}$	87.7%
Output ripple with optional filter	V _{IN} = 12 V, I _O = 175 mA	40 mV _{PP}

8.2.1.2 Detailed Design Procedure

CALCULATION	STEP UP	STEP DOWN	VOLTAGE INVERTING
t _{on} /t _{off}	$\frac{V_{out} + V_F - V_{in(min)}}{V_{in(min)} - V_{sat}}$	$\frac{V_{out} \ ^{+} \ V_{F}}{V_{in(min)} \ ^{-} \ V_{sat} \ ^{-} \ V_{out}}$	$\frac{V_{out} + V_{F}}{V_{in} - V_{sat}}$
$(t_{on} + t_{off})$	<u>1</u> f	1 f	<u>1</u> f
t _{off}	$\frac{t_{\text{on}} + t_{\text{off}}}{\frac{t_{\text{on}}}{t_{\text{off}}}} + 1$	$\frac{t_{\text{on}} + t_{\text{off}}}{\frac{t_{\text{on}}}{t_{\text{off}}}} + 1$	$\frac{t_{\text{on}} + t_{\text{off}}}{\frac{t_{\text{on}}}{t_{\text{off}}} + 1}$
t _{on}	$(t_{on} + t_{off}) - t_{off}$	$(t_{on} + t_{off}) - t_{off}$	$(t_{on} + t_{off}) - t_{off}$
C _T	$4 \times 10^{-5} t_{on}$	$4 \times 10^{-5} t_{on}$	$4 \times 10^{-5} t_{on}$
I _{pk(switch)}	$2I_{out(max)} \left(\frac{t_{on}}{t_{off}} + 1 \right)$	2I _{out(max)}	$2I_{out(max)}\left(\frac{t_{on}}{t_{off}} + 1\right)$
R _{SC}	0.3 I _{pk(switch)}	0.3 I _{pk(switch)}	0.3 I _{pk(switch)}
L _(min)	$\left(\!$	$\left(\!$	$\left(\frac{\left(V_{in(min)} - V_{sat}\right)}{I_{pk(switch)}}\right)t_{on(max)}$



CALCULATION	STEP UP	STEP DOWN	VOLTAGE INVERTING
Co	$9 \frac{I_{out}^{t_{on}}}{V_{ripple(pp)}}$	$\frac{I_{pk(switch)}(t_{on} + t_{off})}{8V_{ripple(pp)}}$	$9 \frac{I_{out}t_{on}}{V_{ripple(pp)}}$

8.2.1.3 Application Curve

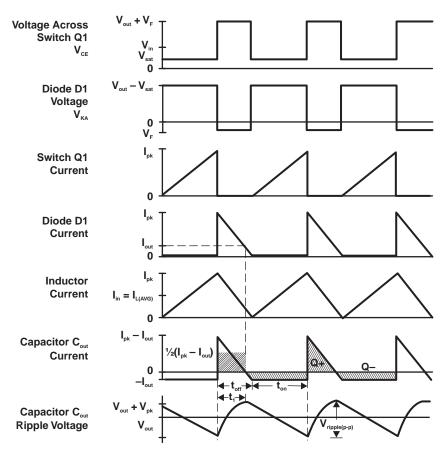


Figure 12. Boost Switching Regulator Waveforms



8.2.2 Step-Down Converter

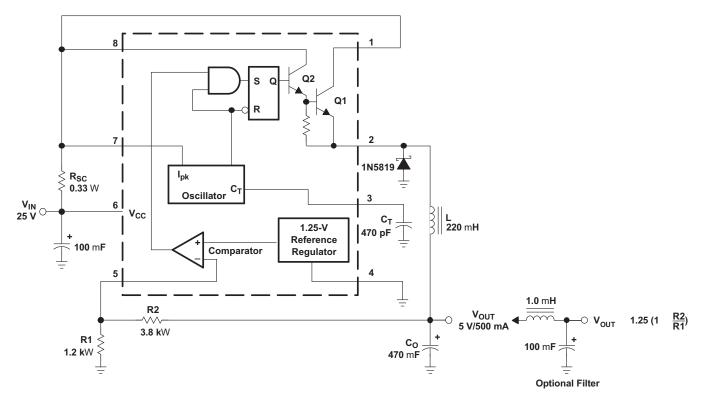


Figure 13. Step-Down Converter

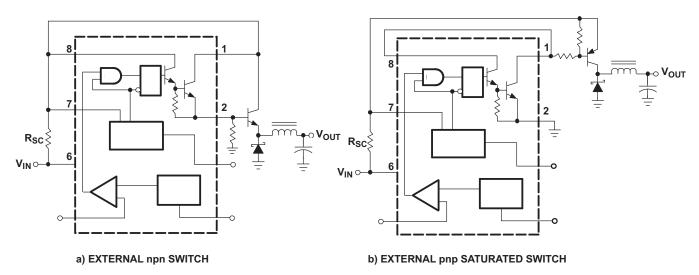


Figure 14. External Current-Boost Connections for I_C Peak Greater Than 1.5 A

Copyright © 2005–2014, Texas Instruments Incorporated



8.2.2.1 Design Requirements

Table 2. Step-Down Converter

TEST	CONDITIONS	RESULTS
Line regulation	$V_{IN} = 15 \text{ V to } 25 \text{ V}, I_{O} = 500 \text{ mA}$	12 mV ± 0.12%
Load regulation	$V_{IN} = 25 \text{ V}, I_{O} = 50 \text{ mA to } 500 \text{ mA}$	3 mV ± 0.03%
Output ripple	V _{IN} = 25 V, I _O = 500 mA	120 mV _{PP}
Short-circuit current	$V_{IN} = 25 \text{ V}, \text{ RL} = 0.1 \Omega$	1.1 A
Efficiency	V _{IN} = 25 V, I _O = 500 mA	83.7%
Output ripple with optional filter	V _{IN} = 25 V, I _O = 500 mA	40 mV _{PP}

8.2.2.2 Detailed Design Procedure

See Detailed Design Procedure.

8.2.2.3 Application Curves

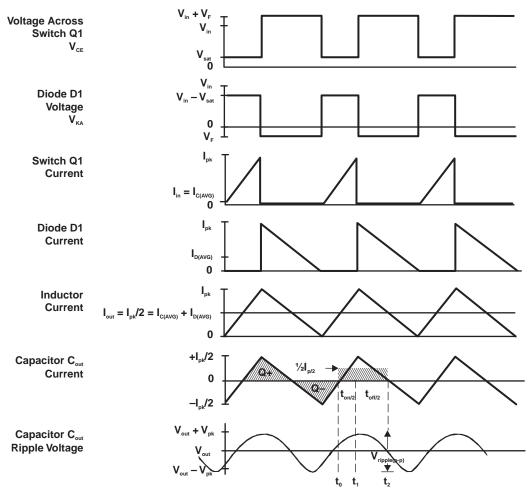


Figure 15. Buck Switching Regulator Waveforms



8.2.3 Voltage Inverter Converter

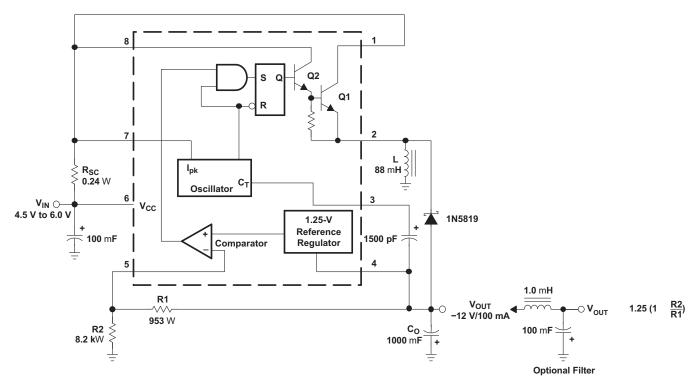


Figure 16. Voltage-Inverting Converter

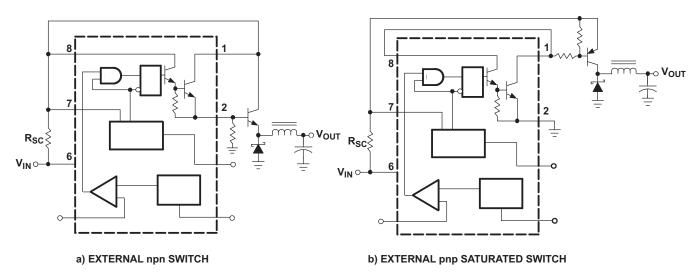


Figure 17. External Current-Boost Connections for Voltage Inverter Converter

Copyright © 2005–2014, Texas Instruments Incorporated



8.2.3.1 Design Requirements

TEST	CONDITIONS	RESULTS
Line regulation	$V_{IN} = 4.5 \text{ V to 6 V}, I_{O} = 100 \text{ mA}$	3 mV ± 0.12%
Load regulation	$V_{IN} = 5 \text{ V}, I_{O} = 10 \text{ mA to } 100 \text{ mA}$	0.022 V ± 0.09%
Output ripple	$V_{IN} = 5 \text{ V}, I_{O} = 100 \text{ mA}$	500 mVPP
Short-circuit current	$V_{IN} = 5 \text{ V}, \text{ R}_{L} = 0.1 \Omega$	910 mA
Efficiency	$V_{IN} = 5 \text{ V}, I_{O} = 100 \text{ mA}$	62.2%
Output ripple with optional filter	V _{IN} = 5 V, I _O = 100 mA	70 mVPP

8.2.3.2 Detailed Design Procedure

See Detailed Design Procedure.

8.2.3.3 Application Curves

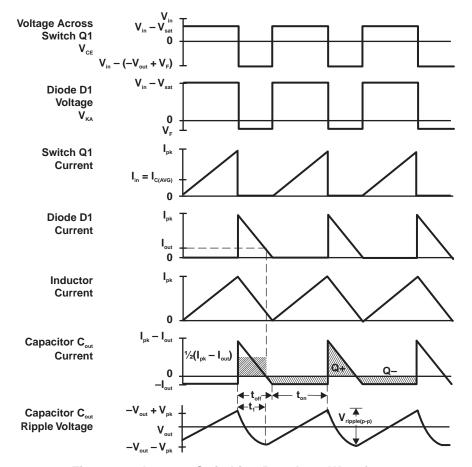


Figure 18. Inverter Switching Regulator Waveforms



8.2.4 12 V Battery Based Automotive Supply

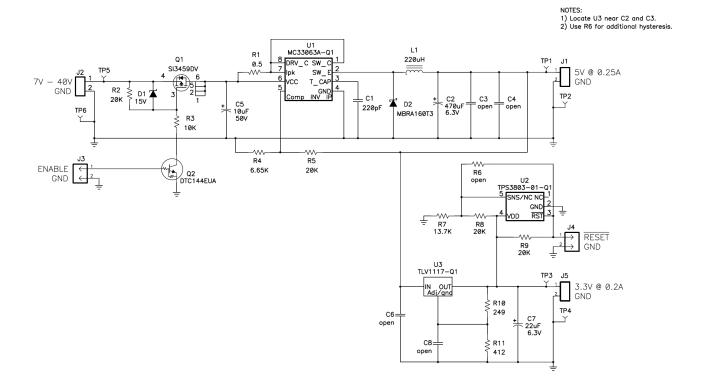


Figure 19. 12 V Battery Based Automotive Supply Schematic

8.2.4.1 Design Requirements

Input Supply Voltage: 7 to 40 V

Output Supply Voltage: 5 V at 0.25 A

An additional supply rail of 3.3 at 0.2 A along with a power supply supervisor is required for this application.

8.2.4.2 Detailed Design Procedure

See Detailed Design Procedure.

Submit Documentation Feedback Product Folder Links: MC33063A-Q1

8.2.4.3 Application Curve

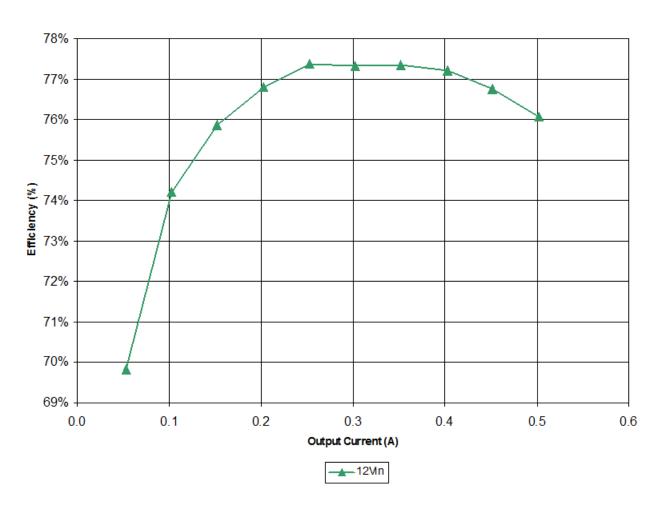


Figure 20. Application Example 4 Efficiency

9 Power Supply Recommendations

The input decoupling capacitors must be located as close as possible to the MC33063-Q1. In addition, the voltage set-point resistor divider components must also be kept close to the IC to eliminate any noise pick-up into the feedback loop.



10 Layout

10.1 Layout Guidelines

Layout is a critical portion of good power supply design. There are several signals paths that conduct fast changing currents or voltages that can interact with stray inductance or parasitic capacitance to generate noise or degrade the power supplies performance. To help eliminate these problems, the input voltage pin should be bypassed to ground with a low ESR ceramic bypass capacitor with X5R or X7R dielectric. Care should be taken to minimize the loop area formed by the bypass capacitor connections, the input pin, and the anode of the catch diode.

10.2 Layout Example

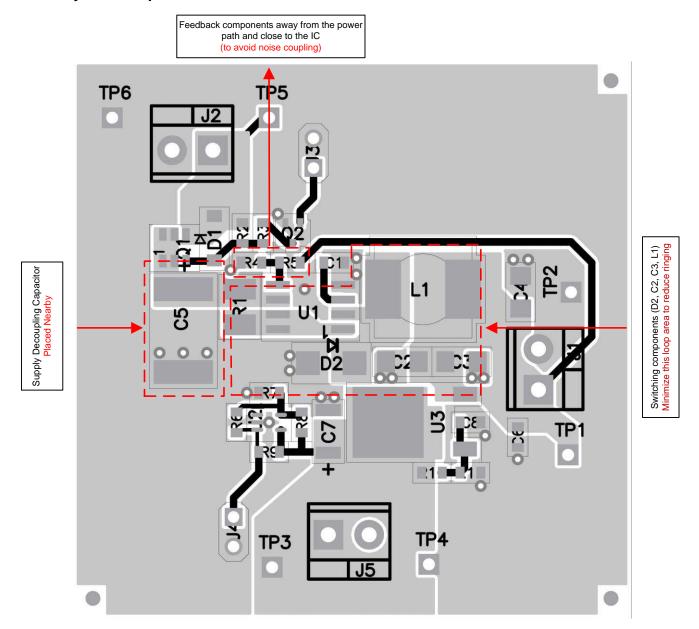


Figure 21. MC33063A-Q1 Layout Top Layer Example

Copyright © 2005–2014, Texas Instruments Incorporated

Layout Example (continued)

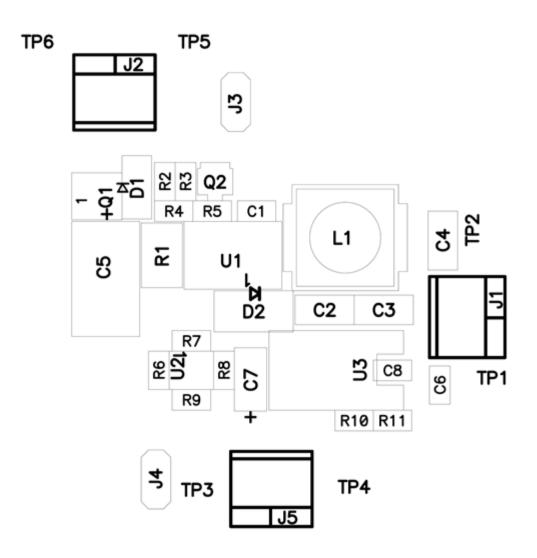
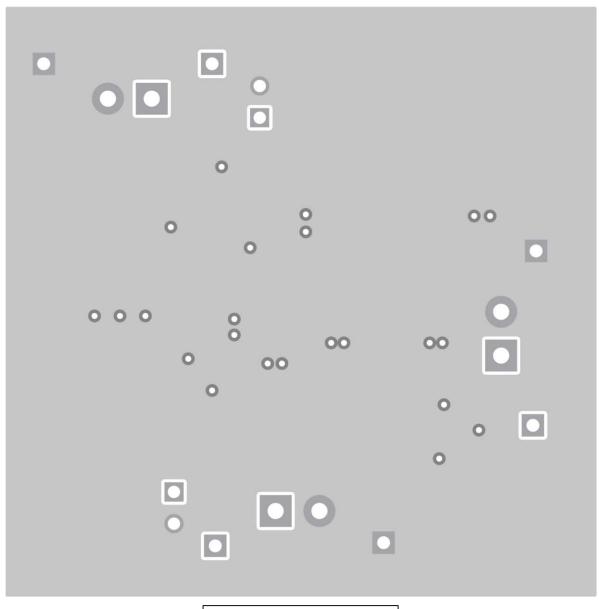


Figure 22. MC33063A-Q1 Layout Middle Layer Example



Layout Example (continued)

Multiple vias connect the input and output to the ground plane



Large ground plane to reduce noise and ground-loop errors

Figure 23. MC33063A-Q1 Layout Bottom Layer Example



11 Device and Documentation Support

11.1 Trademarks

All trademarks are the property of their respective owners.

11.2 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

11.3 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



PACKAGE OPTION ADDENDUM

12-Oct-2014

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
MC33063AQDRQ1	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	33063AQ	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.





12-Oct-2014

OTHER QUALIFIED VERSIONS OF MC33063A-Q1:

NOTE: Qualified Version Definitions:

• Catalog - TI's standard catalog product

D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.



IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products Applications

Audio www.ti.com/audio Automotive and Transportation www.ti.com/automotive Communications and Telecom Amplifiers amplifier.ti.com www.ti.com/communications **Data Converters** dataconverter.ti.com Computers and Peripherals www.ti.com/computers **DLP® Products** www.dlp.com Consumer Electronics www.ti.com/consumer-apps

DSP **Energy and Lighting** dsp.ti.com www.ti.com/energy Clocks and Timers www.ti.com/clocks Industrial www.ti.com/industrial Interface interface.ti.com Medical www.ti.com/medical logic.ti.com Logic Security www.ti.com/security

Power Mgmt power.ti.com Space, Avionics and Defense www.ti.com/space-avionics-defense

Microcontrollers <u>microcontroller.ti.com</u> Video and Imaging <u>www.ti.com/video</u>

RFID <u>www.ti-rfid.com</u>

OMAP Applications Processors www.ti.com/omap TI E2E Community e2e.ti.com/omap

Wireless Connectivity <u>www.ti.com/wirelessconnectivity</u>

AMEYA360 Components Supply Platform

Authorized Distribution Brand:

























Website:

Welcome to visit www.ameya360.com

Contact Us:

> Address:

401 Building No.5, JiuGe Business Center, Lane 2301, Yishan Rd Minhang District, Shanghai , China

> Sales:

Direct +86 (21) 6401-6692

Email amall@ameya360.com

QQ 800077892

Skype ameyasales1 ameyasales2

Customer Service :

Email service@ameya360.com

Partnership :

Tel +86 (21) 64016692-8333

Email mkt@ameya360.com